



HIGH-SIDE AND LOW-SIDE GATE DRIVER IN SO-8

Description

The DGD2181 is a high-voltage / high-speed gate driver capable of driving N-Channel MOSFETs and IGBTs in a half-bridge configuration. High-voltage processing techniques enable the DGD2181's high-side to switch to 600V in a bootstrap operation.

The DGD2181 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) for easy interfacing with controlling devices. The driver outputs feature high-pulse current buffers designed for minimum driver cross conduction.

The DGD2181 is offered in SO-8 package and the operating temperature extends from -40°C to +125°C.

Applications

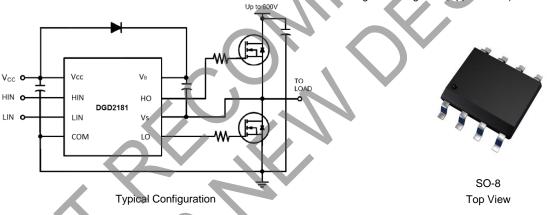
- **DC-DC Converters**
- **DC-AC Inverters**
- **AC-DC Power Supplies**
- Motor Controls
- **Class D Power Amplifiers**

Features

- Floating High-side Driver in Bootstrap Operation to 600V
- Drives two N-Channel MOSFETs or IGBTs in a Half Bridge Configuration
- 1.9A Source / 2.3A Sink Output Current Capability
- Outputs Tolerant to Negative Transients
- Wide Low-side Gate Driver and Logic Supply: 10V to 20V
- Logic Input (HIN and LIN) 3.3V Capability
- Schmitt Triggered Logic Inputs with Internal Pull Down
- Undervoltage Lockout for High and Low Side Drivers
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3) For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.
- https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: SO-8 (Type TH)
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 🕄
 - Weight: 0.075 grams (Approximate)



Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel			
DGD2181S8-13 DGD2181 13 12 2,500							
lotes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.							

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

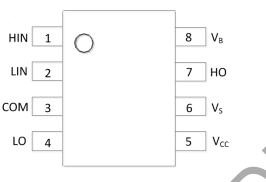
Marking Information



∃ = Manufacturer's Marking DGD2181 = Product Type Marking Code YY = Year (ex: 19 = 2019)WW = Week (01 to 53)



Pin Diagrams

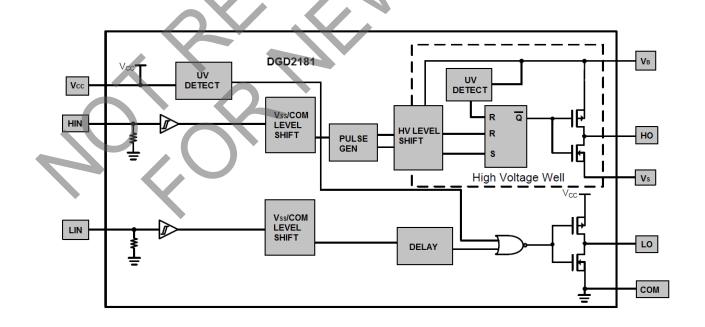


Top View SO-8

Pin Descriptions

Pin Number	Pin Name	Function
1	HIN	Logic input for high-side gate driver output, in phase with HO
2	LIN	Logic input for low-side gate driver output, in phase with LO
3	COM	Low-side and logic return
4	LO	Low-side gate drive output
5	Vcc	Low-side and logic fixed supply
6	Vs	High-side floating supply return
7	HO	High-side gate drive output
8	VB	High-side floating supply

Functional Block Diagram





NOT RECOMMENDED FOR NEW DESIGN USE <u>DGD2181M</u>

DGD2181

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-side Floating Supply Voltage	VB	-0.3 to +624	V
High-side Floating Supply Offset Voltage	Vs	V _B -24 to V _B +0.3	V
High-side Floating Output Voltage	V _{HO}	V _S -0.3 to V _B +0.3	V
Offset Supply Voltage Transient	dV _S / dt	50	V/ns
Low-side Fixed Supply Voltage	V _{CC}	-0.3 to +24	V
Low-side Output Voltage	V _{LO}	-0.3 to V _{CC} +0.3	V
Logic Input Voltage (HIN and LIN)	V _{IN}	-0.3 to V _{CC} +0.3	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	PD	0.625	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	200	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	T _{STG}	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Parameter		Symbol	Min	Max	Unit
High-side Floating Supply Absolute Voltage		VB	V _S + 10	V _S + 20	V
High-side Floating Supply Offset Voltage		Vs	(Note 6)	600	V
High-side Floating Output Voltage		Vно	Vs	VB	V
Low-side Fixed Supply Voltage		Vcc	10	20	V
Low-side Output Voltage		VLO	0	Vcc	V
Logic Input Voltage (HIN and LIN)		VIN	0	5	V
Ambient Temperature		TA	-40	+125	C°

Note: 6. Logic operation for V_S of -5V to +600V.





Notes:

DC Electrical Characteristics (V_{BLAS} (V_{CC} , V_{BS}) = 15V, $@T_A = +25^{\circ}C$, unless otherwise specified.) (Note 7)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "1" Input Voltage (Note 8)	VIH	2.5	-	_	V	$V_{CC} = 10V$ to 20V
Logic "0" Input Voltage (Note 8)	VIL	—	_	0.8	V	$V_{CC} = 10V$ to 20V
High Level Output Voltage, V _{BIAS} - V _O	Vон	—	-	1.4	V	$I_O = 0 m A$
Low Level Output Voltage, V _O	V _{OL}	—	-	0.2	V	I _O = 20mA
Offset Supply Leakage Current	I _{LK}	—	_	50	μA	$V_{B} = V_{S} = 600V$
Quiescent V _{BS} Supply Current	I _{BSQ}	20	60	150	μA	$V_{IN} = 0V \text{ or } 5V$
Quiescent V _{CC} Supply Current	ICCQ	50	120	240	μA	$V_{IN} = 0V \text{ or } 5V$
Logic "1" Input Bias Current	I _{IN+}	—	25	60	μA	VIN = 5V
Logic "0" Input Bias Current	I _{IN-}	—	-	5.0	μA	$V_{IN} = 0V$
V _{BS} Supply Undervoltage Positive Going Threshold	V _{BSUV+}	8.0	8.9	9.8	V	_
V _{BS} Supply Undervoltage Negative Going Threshold	V _{BSUV-}	7.4	8.2	9.0	V	
V _{CC} Supply Undervoltage Positive Going Threshold	V _{CCUV+}	8.0	8.9	9.8	V	—
V _{CC} Supply Undervoltage Negative Going Threshold	V _{CCUV} -	7.4	8.2	9.0	V	—
Output High Short Circuit Pulsed Current	I _{O+}	1.4	1.9	$\langle - \rangle$	A	V _O = 0V, PW ≤ 10µs
Output Low Short Circuit Pulsed Current	I _{O-}	1.7	2.3		A	V _O = 15V, PW ≤ 10µs

 The V_{IN} and I_{IN} parameters are applicable to the two logic input pins: LIN and HIN. The V_O and I_O parameters are applicable to the respective output pins: HO and LO.

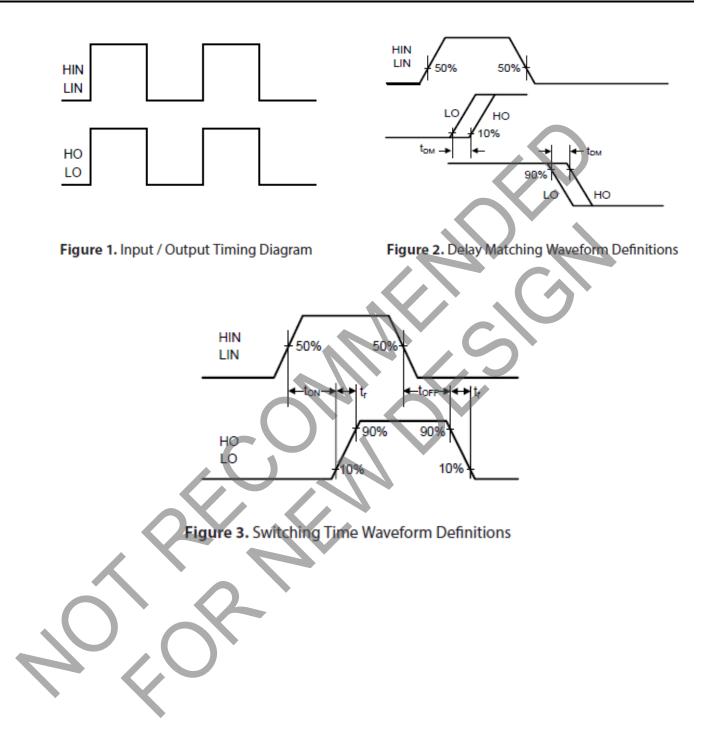
For optimal operation, it is recommended that the input pulses (HIN and LIN) should have a minimum amplitude of 2.5V with a minimum pulse width of 360ns.

AC Electrical Characteristics (V_{BIAS} (V_{CC}, V_{BS}) = 15V, C_L = 1000pF, @T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-on Propagation Delay	ton	—	180	270	ns	$V_{\rm S} = 0V$
Turn-off Propagation Delay	toff	—	220	330	ns	$V_S = 0V \text{ or } 600V$
Delay Matching, HO & LO Turn-on/off	t _{DM}	_	—	35	ns	—
Turn-on Rise Time	t _R	-	40	60	ns	$V_{\rm S} = 0V$
Turn-off Fall Time	tF	—	20	35	ns	$V_S = 0V$



Timing Waveforms





Typical Performance Characteristics (@T_A = +25°C, V_{CC} = 15V, unless otherwise specified.)



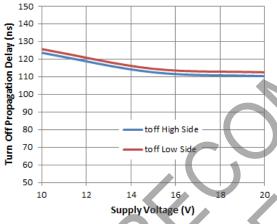
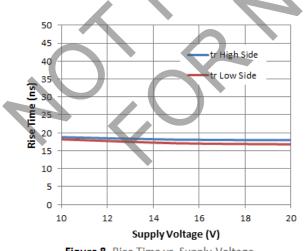
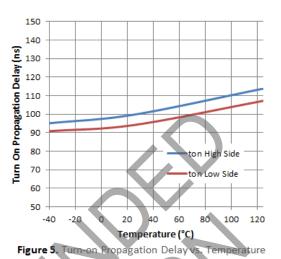
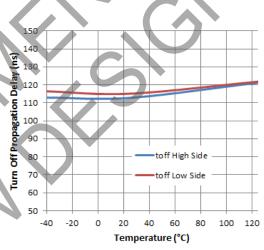


Figure 6. Turn-off Propagation Delay vs Supply Voltage

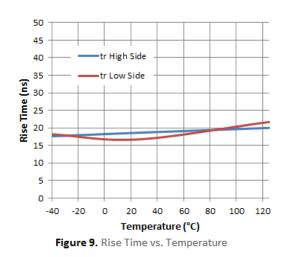






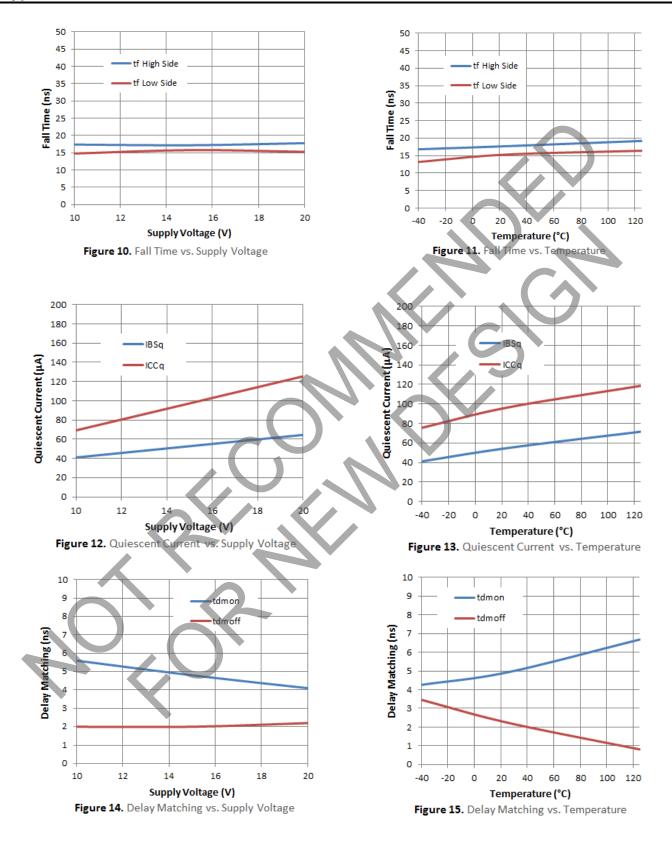






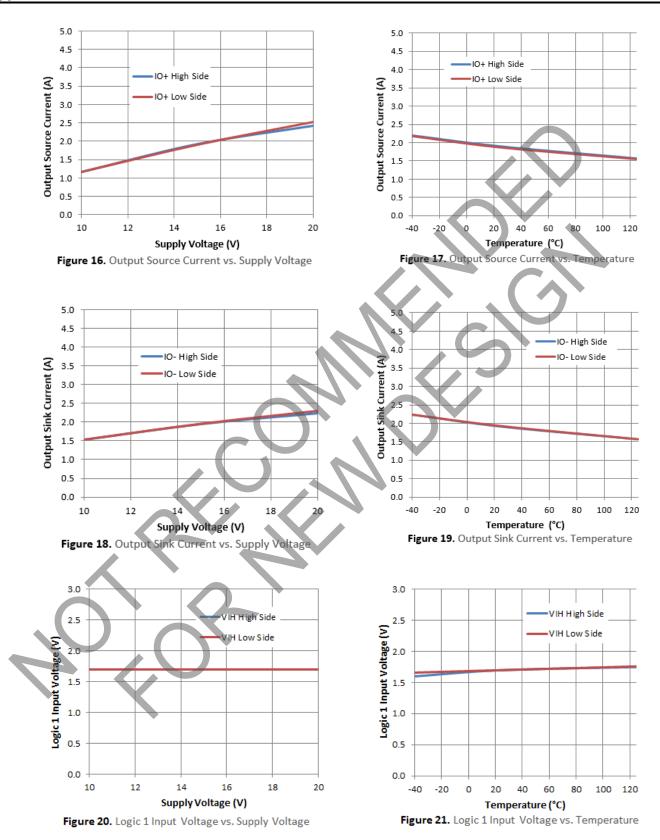


Typical Performance Characteristics (continued)





Typical Performance Characteristics (continued)





Typical Performance Characteristics (continued)

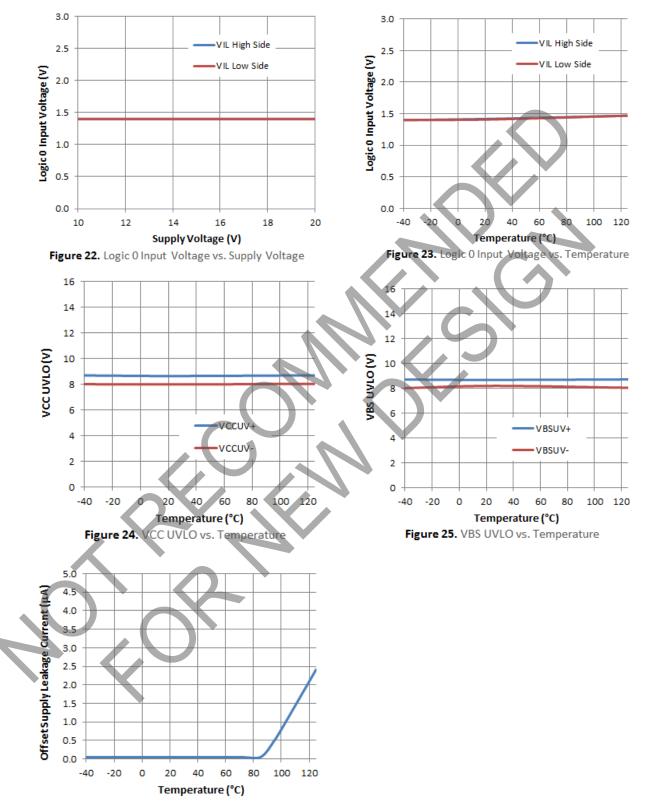


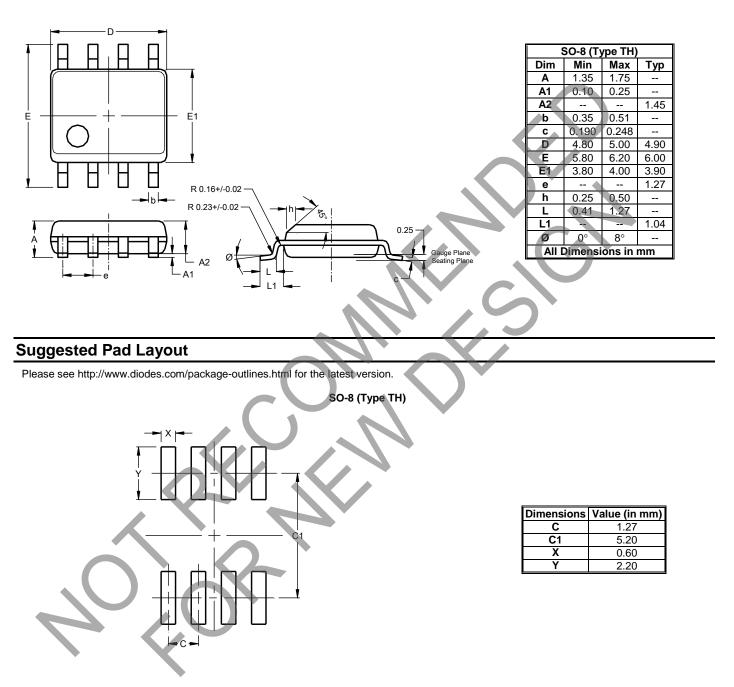
Figure 26. Offset Supply Leakage Current vs. Temperature



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8 (Type TH)



Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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